
Quantum Oscillations in the Layer Structure of Thin Metal Films

An x-ray study of smooth Pb/Si(111) films

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Electronic Effects in Metal Films

- ▶ For low temperatures, ultrathin metal films exhibit quantum size effects when approaching the atomic scale
- ▶ Significant electronic contributions to film energetics have been demonstrated
 - ⇒ Self-organized “mesas” of preferred heights (Pb/Si, Ag/Si, Pb/Cu)
 - ⇒ Smooth films (Ag/GaAs, Ag/Fe)
- ▶ Electron confinement may cause structural effects as well
 - ⇒ Modulations in step height have been observed in STM and HAS studies
 - These techniques only sense the top surface morphology
 - X rays penetrate whole film, all the atomic layers of the film are probed as well as the film/substrate interface

**What is the nature of any induced structural distortions
of the atomic lattice?**

Free Electron Model

Consider a 3-D free-electron gas confined to a 1-D quantum box:

$$\Psi_{\mathbf{k}}(\mathbf{r}) \propto e^{i(k_x x + k_y y)} \sin(k_z z)$$

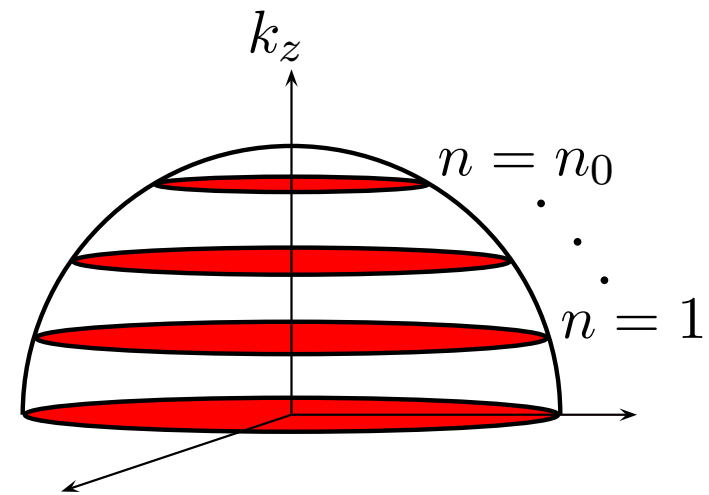
Charge density:

$$\rho(z) \propto \sum_{n=1}^{n_0} \pi (k_F^2 - k_z^2) \sin^2(k_z z)$$

Self-normalized density variations:

$$\begin{aligned} \delta\rho(z) &\equiv \frac{\rho(z) - \langle \rho(z) \rangle_z}{\langle \rho(z) \rangle_z} \\ &= -\frac{1}{C_D} \left(k_F^2 + \frac{1}{4} \frac{\partial^2}{\partial z^2} \right) \sum_{n=1}^{n_0} \cos\left(\frac{2\pi z}{D} n\right) \end{aligned}$$

n_0 -slit interference pattern with $\lambda \approx \pi/k_F = \lambda_F/2$.

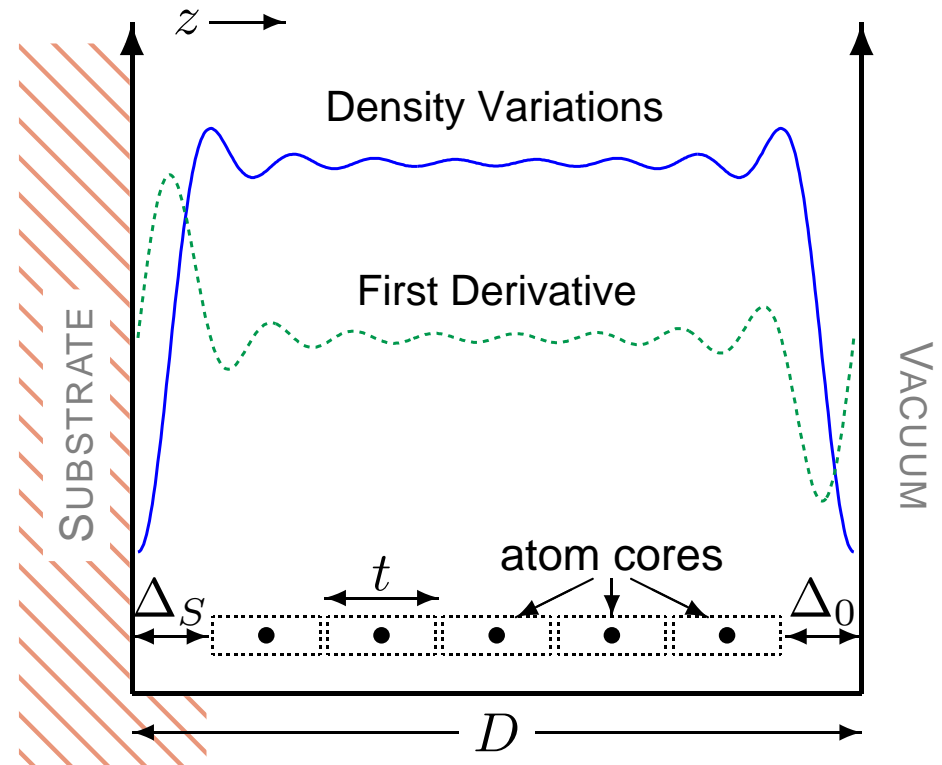


Fermi sphere with subbands at

$$k_z = \frac{n\pi}{D}$$

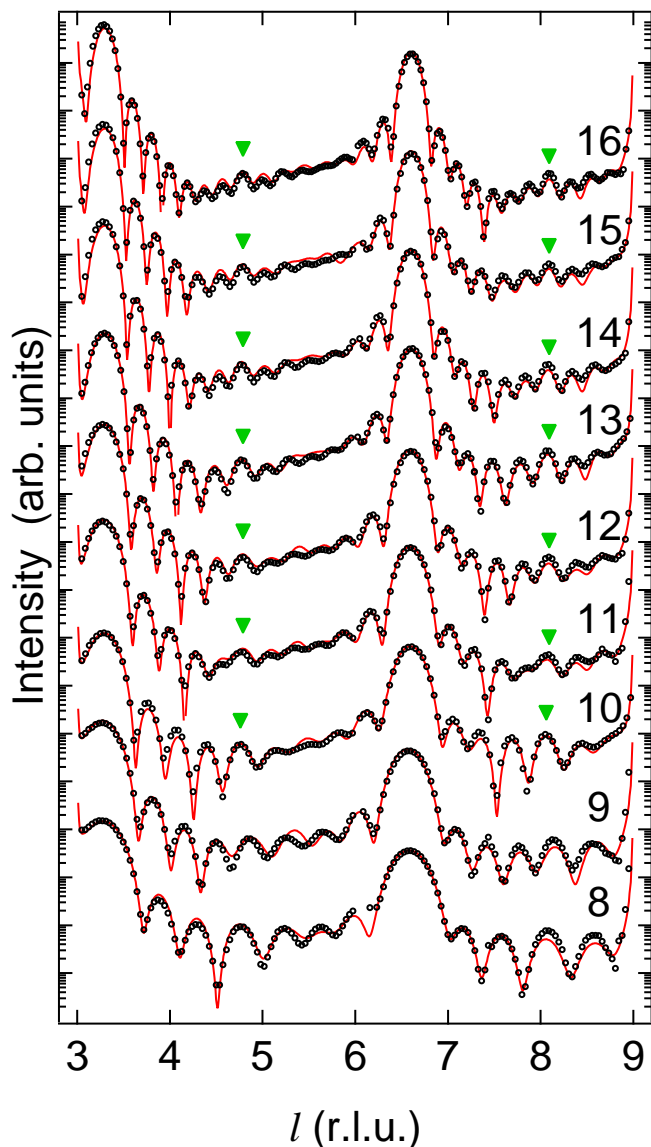
Charge Density in Pb/Si(111) Films

- ▶ Atoms shift from ideal positions
 $\Delta z \propto \frac{\partial}{\partial z} \delta \rho(z)$
- ▶ 4 parameter model for lattice distortions: Δ_S, Δ_0, t, A
- ▶ Layer-by-layer growth was found for ultrathin Pb films grown on the Pb/Si(111)- $\sqrt{3} \times \sqrt{3}$ - β interface at low temperatures (110 K)
 - ⇒ 1-D Electron confinement
 - ⇒ Uniform quantum wells
 - ⇒ Δ_S, Δ_0, t, A may be thickness-dependent



Electrons are confined to a quantum box of width $D = \Delta_S + Nt + \Delta_0$

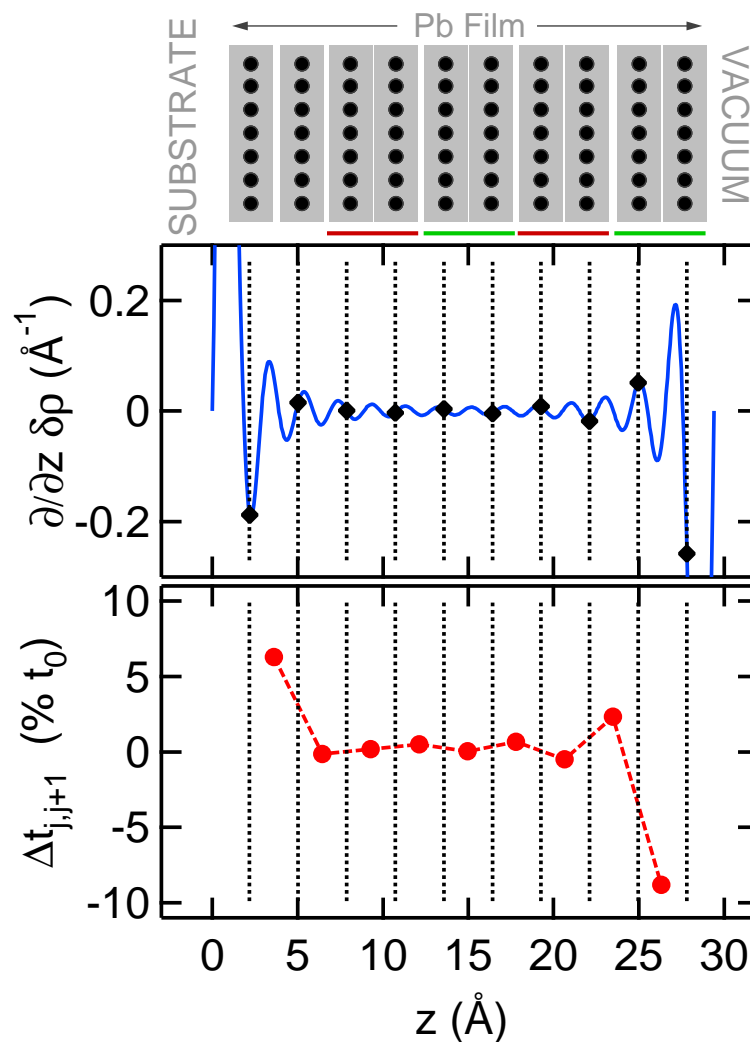
Extended X-ray Reflectivity Data



- ▶ Scattering from high l values gives sub-Å structural information
- ▶ Data was taken for $N = 6 - 18$ AL and $l = 0.2 - 12$ r.l.u.
- ▶ Spectra all have features at the $\frac{1}{2}$ -order point for Pb(111)
 - ⇒ Analogous to fractional-order peaks for surface reconstructions
 - ⇒ Indicative of a quasibilayer superperiodicity in z direction
 - $\lambda_F/2 \approx \frac{2}{3}$ AL
 - ⇒ Reproduced well by kinematic model using $\delta\rho$ lattice distortions

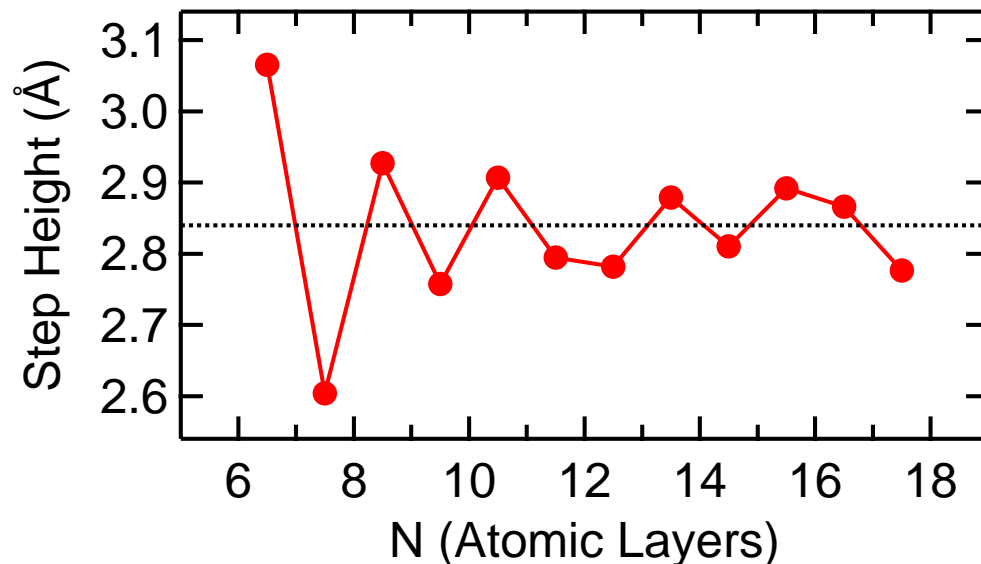
Structural Distortions of Atomic Layers

- ▶ Fits to data reveal variations in the interlayer spacings between individual atomic layers
 - ▶ Quasibilayer oscillations are evident near film surface
 - ▶ Significant distortion of film lattice near the substrate as well
 - ▶ Distortions are qualitatively similar for the range of thicknesses
- ⇒ Top interlayer spacing always compressed, etc.



Structural variations for $N=10$

Comparison to Previous Studies



- ▶ Step heights were deduced by taking the difference between net film thicknesses differing by 1 AL
 - ⇒ Net film thickness $\equiv \sum$ adjusted t 's + Δ_0 (spillage into vacuum)
- ▶ Quasibilayer oscillations are present
- ▶ Similar to results from previous STM and HAS studies

Summary

- ▶ Interference of electron standing waves in metallic quantum well
 - ⇒ Charge density oscillations
 - ⇒ Structural distortions of the atomic lattice
- ▶ Lattice modulations are present at both film interfaces
- ▶ Step height modulations arise from subtle expansions and contractions due to different sized quantum wells
- ▶ Lattice distortions can be expected in metallic nanostructures

For more information see P. Czoschke et al. *PRL* **91** 226801 (2003)

